

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:)	Confirmation No.: 1477
Akira ISHIKAWA)	Examiner: Thao P. Le
Application No. 10/668,969)	Group Art Unit: 2818
Filed: September 24, 2003)	
For: SEMICONDUCTOR DEVICE AND)	August 8, 2005
MANUFACTURING METHOD THEREOF)	

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure as set forth in 37 C.F.R. §1.56, Applicant hereby submits the following information in conformance with 37 C.F.R. §§ 1.97 and 1.98. No copy of the U.S. documents have been supplied with this Information Disclosure Statement in accordance with Official Gazette Notice dated August 5, 2003. Pursuant to 37 C.F.R. §1.98, a copy of each of the other documents cited is enclosed.

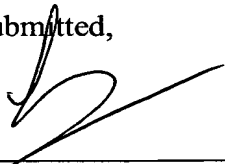
The Commissioner is hereby authorized to charge the fees connected with this filing, in the amount of \$180.00 which is required now, or credit any overpayment to Deposit Account No. 19-2380 [740756-2653] in compliance with the provisions of 37 C.F.R. § 1.97(c).

The references cited in the attached form PTO-1449 were cited in a related application Serial No. 10/670,310, which is U.S. Patent Publication No. 2004-0063256 also listed in the form.

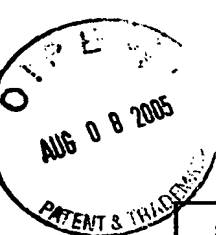
It is requested that the accompanying PTO-1449 be considered and made of record in the above-identified application. To assist the Examiner, the documents are listed on the attached form PTO-1449. It is respectfully requested that the Examiner initial a copy of this form and return it to the undersigned.

Respectfully submitted,

By: _____


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Substitute for form 1449A/PTO

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(use as many sheets as necessary)

Complete if Known

Application Number	10/668,969
Filing Date	September 24, 2003
First Named Inventor	Akira ISHIKAWA
Art Unit	2818
Examiner Name	Thao P. Le
Attorney Docket Number	740756-2653

Sheet	1	of	1
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U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	U.S. Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code ² (if known)			
		US-5049514	09-17-1991	MORI	
		US-5079617	01-07-1992	YONEDA	
		US-5276347	01-04-1994	WEI et al.	
		US-5413961	05-09-1995	KIM	
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		US-5767006	06-16-1998	LEE	
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		US-2004-0063256	04-01-2004	ISHIKAWA	
		US-			
		US-			

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Country Code ³ Number ⁴ Kind Code ⁵ (if known)				
		JP-63-275181	OHOKA	11-11-1988		Abstract

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
		Huang et al., "A Novel Submicron LDD Transistor with Inverse-T Gate Structure", IEDM, 1986, pp 742-745, 1986.	

Examiner Signature		Date Considered	
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at 222.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.